

## Product Summary

| $V_{RRM}$ (V) | $I_O$ (A) | $V_F$ MAX (V) | $I_R$ MAX (mA) |
|---------------|-----------|---------------|----------------|
| 100           | 6         | 0.74          | 0.1            |

## Description

The SBR6100CTLQ is dual center tap rectifier in TO252 (DPAK) package. Offering excellent high temperature stability and superior avalanche capability, this device is specifically intended for use in automotive applications.

## Applications

- DC/DC Converters
- DC/AC Inverters
- AC/DC Power Supplies

## Features

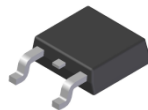
- Low Forward Voltage Drop ( $V_F$ ); Better Efficiency and Cooler Operation
- Reduced High Temperature Reverse Leakage; Increased Reliability against Thermal Runaway Failure in High Temperature Operation
- Excellent High Temperature Stability
- Patented Super Barrier Rectifier (SBR®) Technology
- Soft, Fast Switching Capability
- +150°C Operating Junction Temperature
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **The SBR6100CTLQ is suitable for automotive applications requiring specific change control and is AEC-Q101 qualified, is PPAP capable, and is manufactured in IATF16949 certified facilities.**

<https://www.diodes.com/quality/product-definitions/>

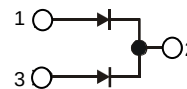
## Mechanical Data

- Package: TO252
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208
- Polarity: See Below
- Weight: 0.33 grams (Approximate)

TO252 (DPAK)



Top View



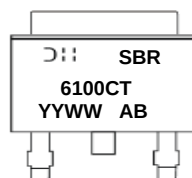
Package Pin-Out Configuration

## Ordering Information (Note 4)

| Part Number    | Package      | Packaging        |
|----------------|--------------|------------------|
| SBR6100CTLQ-13 | TO252 (DPAK) | 2500/Tape & Reel |

- Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
  2. See [http://www.diodes.com/quality/lead\\_free/](http://www.diodes.com/quality/lead_free/) for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

## Marking Information



SBR6100CT = Product Type Marking Code  
 AB = Foundry and Assembly Code  
 YYWW = Date Code Marking  
 YY = Last Two Digits of Year (ex: 19 = 2019)  
 WW = Week (01 to 53)

## Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.  
For capacitive load, derate current by 20%.

| Characteristic                                                                                   | Symbol              | Value | Unit |
|--------------------------------------------------------------------------------------------------|---------------------|-------|------|
| Peak Repetitive Reverse Voltage                                                                  | V <sub>RRM</sub>    | 100   | V    |
| Working Peak Reverse Voltage                                                                     | V <sub>RWM</sub>    |       |      |
| DC Blocking Voltage                                                                              | V <sub>RM</sub>     |       |      |
| RMS Reverse Voltage                                                                              | V <sub>R(RMS)</sub> | 71    | V    |
| Average Rectified Output Current @ T <sub>C</sub> = +115°C                                       | I <sub>O</sub>      | 6     | A    |
| Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load | I <sub>FSM</sub>    | 78    | A    |
| Repetitive Peak Avalanche Power (1μs, +25°C)                                                     | P <sub>ARM</sub>    | 7000  | W    |
| Non-Repetitive Avalanche Energy (T <sub>J</sub> = +25°C, I <sub>AS</sub> = 6A, L = 8.5mH)        | E <sub>AS</sub>     | 120   | mJ   |

## Thermal Characteristics

| Characteristic                                                     | Symbol                            | Value       | Unit |
|--------------------------------------------------------------------|-----------------------------------|-------------|------|
| Maximum Thermal Resistance, Junction to Ambient (Per Leg) (Note 5) | R <sub>θJA</sub>                  | 49          | °C/W |
| Operating and Storage Temperature Range                            | T <sub>J</sub> , T <sub>STG</sub> | -65 to +150 | °C   |

## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic                     | Symbol         | Min | Typ  | Max  | Unit | Test Condition                                 |
|------------------------------------|----------------|-----|------|------|------|------------------------------------------------|
| Forward Voltage Drop (Per Leg)     | V <sub>F</sub> | —   | 0.68 | 0.74 | V    | I <sub>F</sub> = 3A, T <sub>J</sub> = +25°C    |
|                                    |                |     | 0.56 | 0.62 |      | I <sub>F</sub> = 3A, T <sub>J</sub> = +125°C   |
| Leakage Current (Note 6) (Per Leg) | I <sub>R</sub> | —   | —    | 0.1  | mA   | V <sub>R</sub> = 100V, T <sub>J</sub> = +25°C  |
|                                    |                |     |      | 12   |      | V <sub>R</sub> = 100V, T <sub>J</sub> = +125°C |

Notes: 5. Device mounted on Poly substrate PC board, 1oz copper, with minimum recommended pad layout.  
6. Short duration pulse test used to minimize self-heating effect.

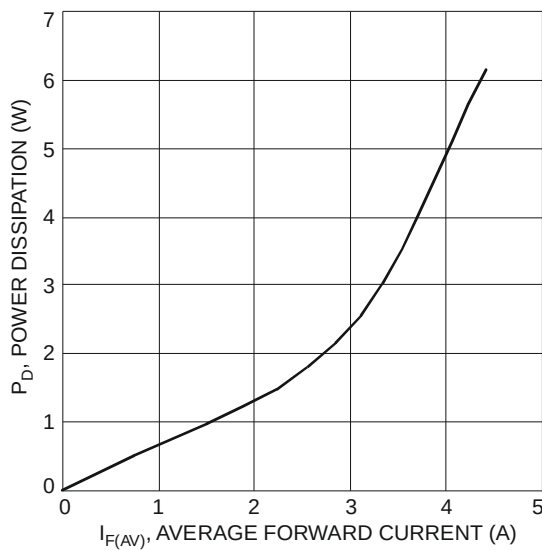


Figure 1 Forward Power Dissipation

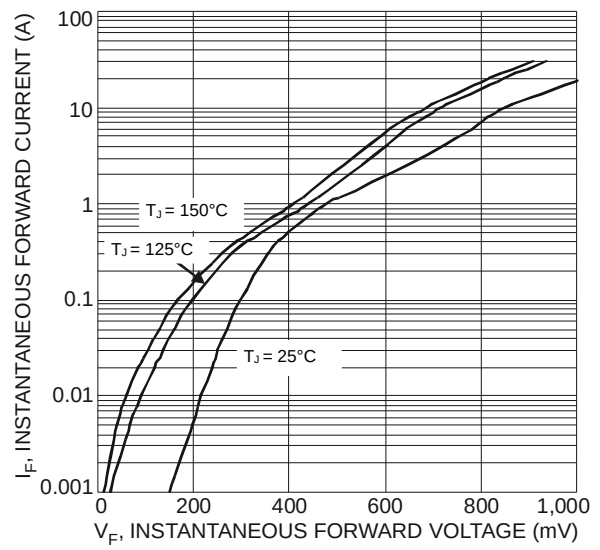
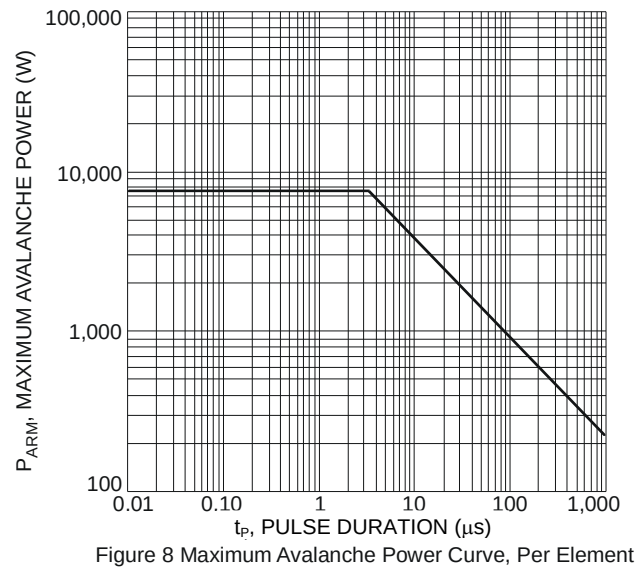
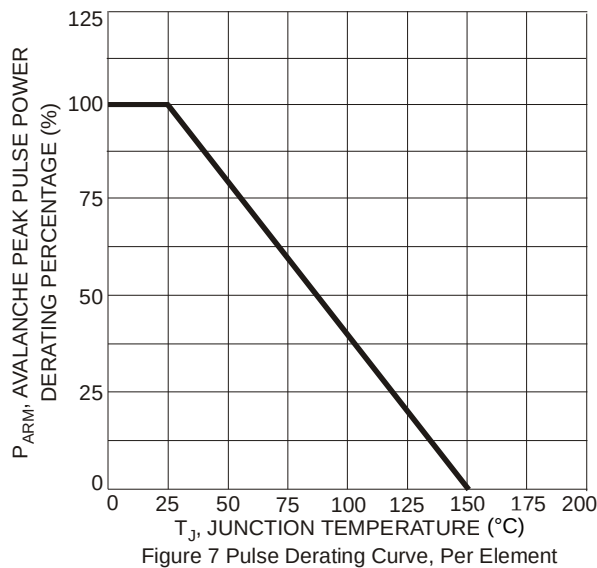
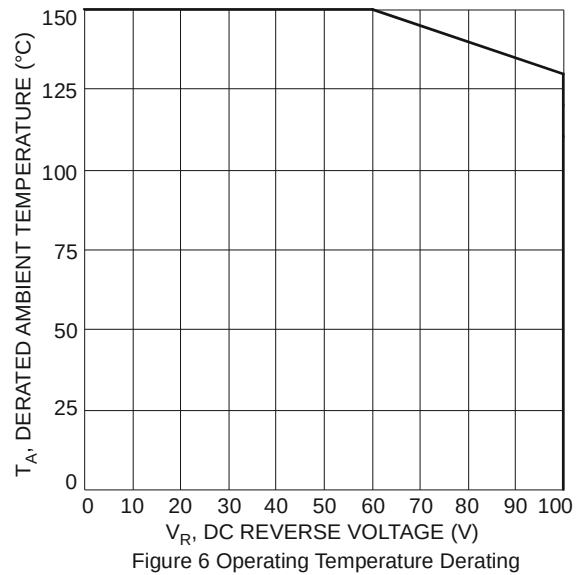
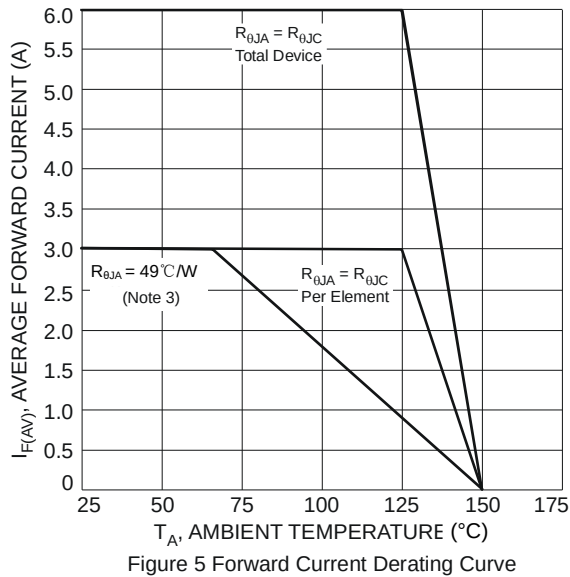
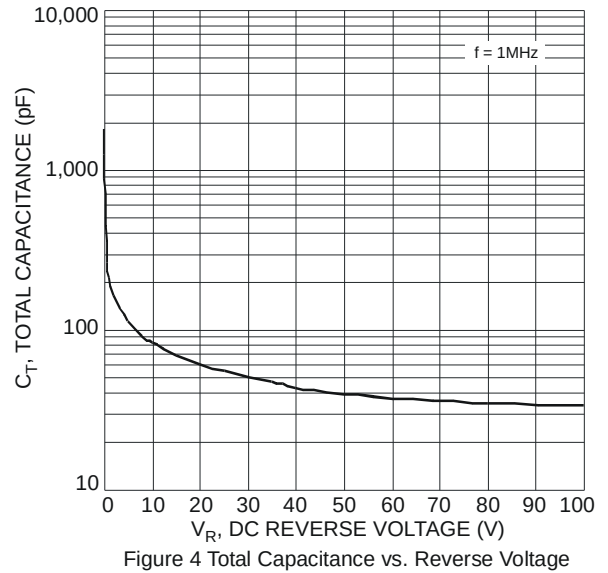
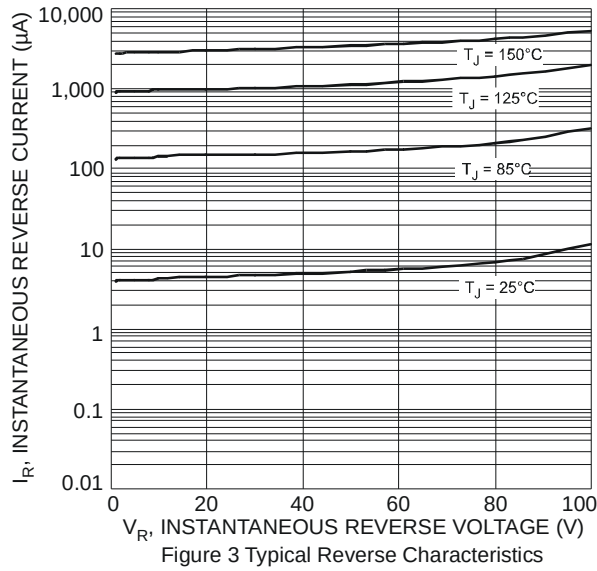


Figure 2 Typical Forward Characteristics



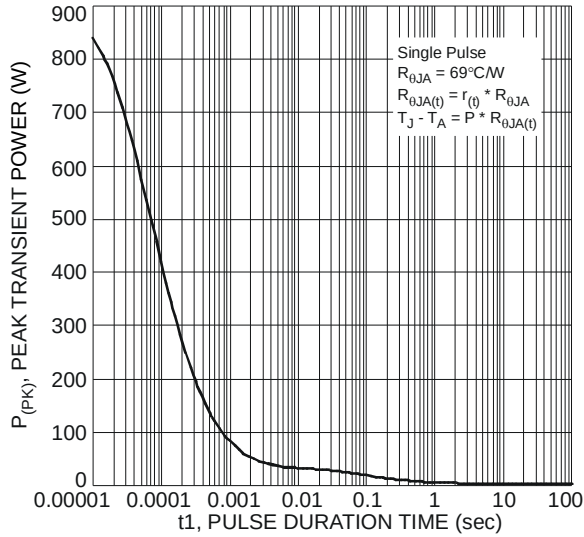


Figure 9 Single Pulse Maximum Power Dissipation

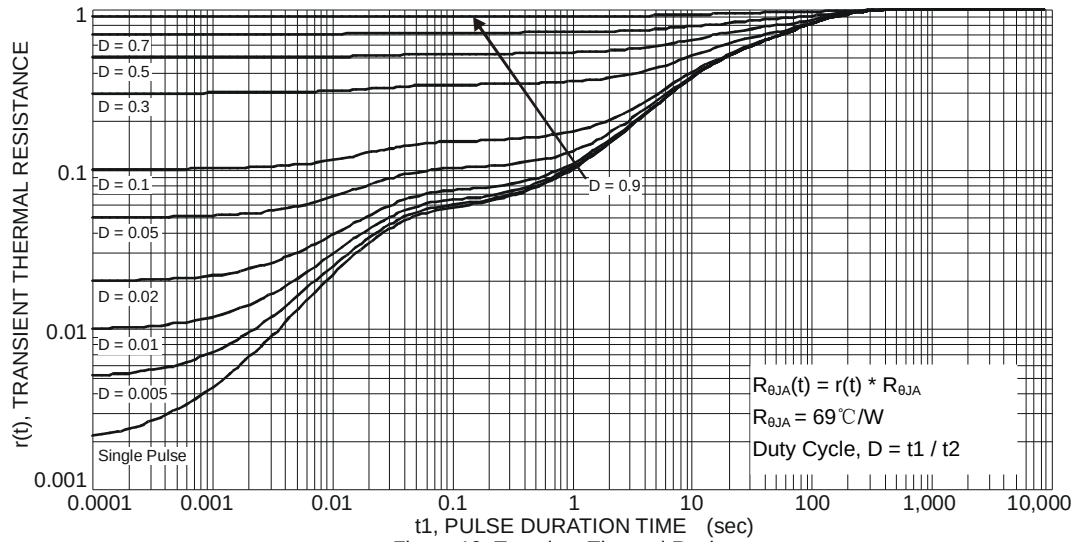
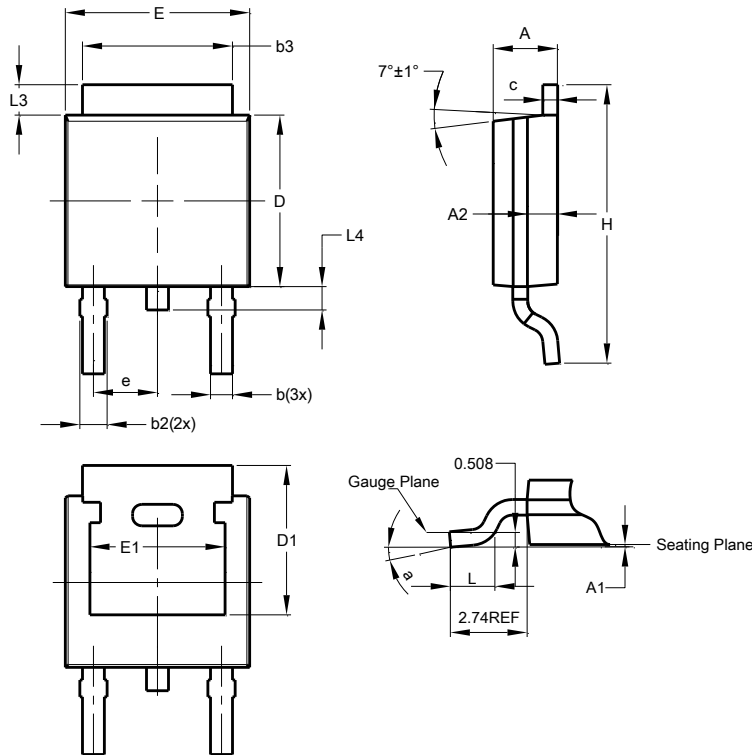


Figure 10 Transient Thermal Resistance

## Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

### TO252 (DPAK)

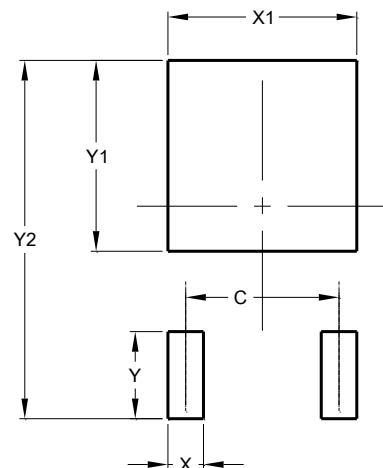


| TO252 (DPAK)         |           |       |       |
|----------------------|-----------|-------|-------|
| Dim                  | Min       | Max   | Typ   |
| A                    | 2.19      | 2.39  | 2.29  |
| A1                   | 0.00      | 0.13  | 0.08  |
| A2                   | 0.97      | 1.17  | 1.07  |
| b                    | 0.64      | 0.88  | 0.783 |
| b2                   | 0.76      | 1.14  | 0.95  |
| b3                   | 5.21      | 5.50  | 5.33  |
| c                    | 0.45      | 0.58  | 0.531 |
| D                    | 6.00      | 6.20  | 6.10  |
| D1                   | 5.21      | --    | --    |
| e                    | 2.286 BSC |       |       |
| E                    | 6.45      | 6.70  | 6.58  |
| E1                   | 4.32      | --    | --    |
| H                    | 9.40      | 10.41 | 9.91  |
| L                    | 1.40      | 1.78  | 1.59  |
| L3                   | 0.88      | 1.27  | 1.08  |
| L4                   | 0.64      | 1.02  | 0.83  |
| a                    | 0°        | 10°   | --    |
| All Dimensions in mm |           |       |       |

## Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

### TO252 (DPAK)



| Dimensions | Value (in mm) |
|------------|---------------|
| C          | 4.572         |
| X          | 1.060         |
| X1         | 5.632         |
| Y          | 2.600         |
| Y1         | 5.700         |
| Y2         | 10.700        |

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